



ALPHA & OMEGA
SEMICONDUCTOR

AO3421E

30V P-Channel MOSFET

General Description

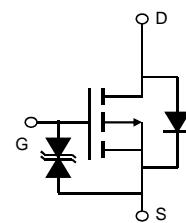
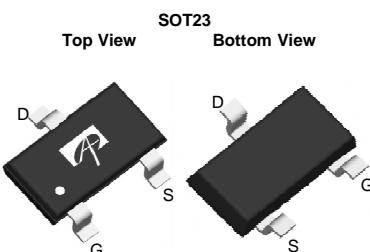
The AO3421E combines advanced trench MOSFET technology with a low resistance package to provide extremely low $R_{DS(ON)}$. This device is ideal for load switch and battery protection applications.

Product Summary

V_{DS}	-30V
I_D (at $V_{GS}=-10V$)	-3A
$R_{DS(ON)}$ (at $V_{GS}=-10V$)	< 95mΩ
$R_{DS(ON)}$ (at $V_{GS}=-4.5V$)	< 160mΩ

Typical ESD protection

HBM Class 2

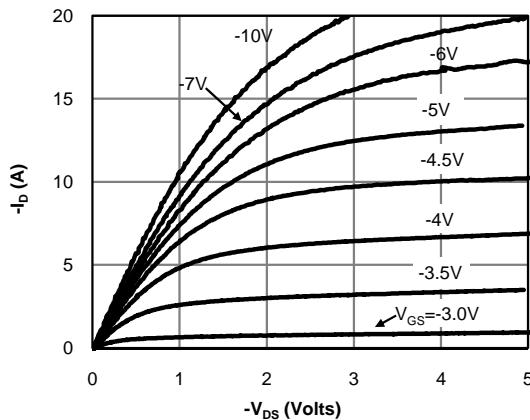
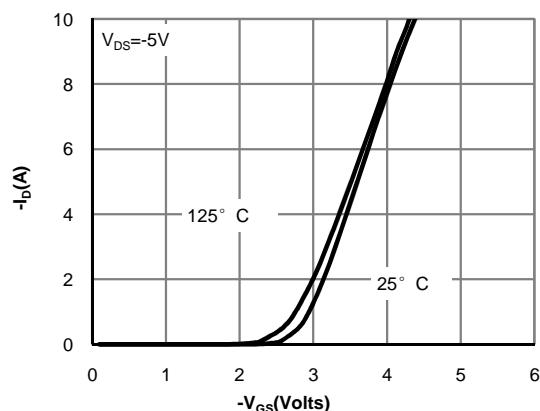
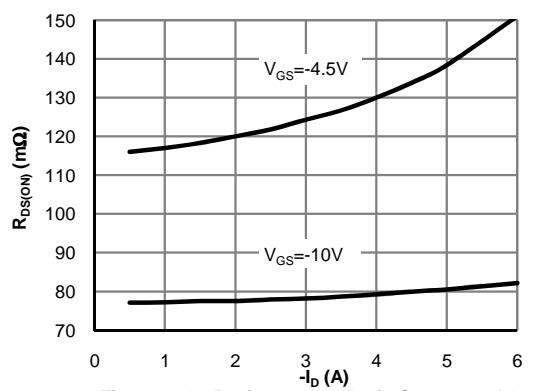
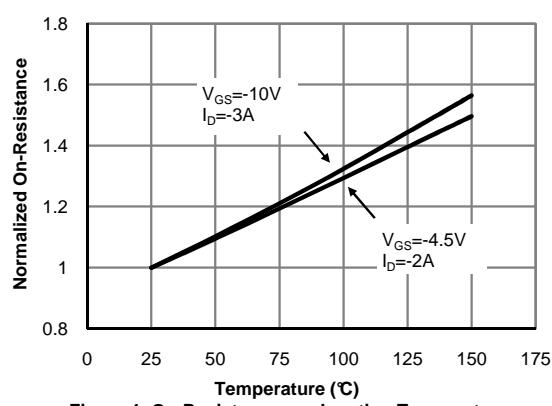
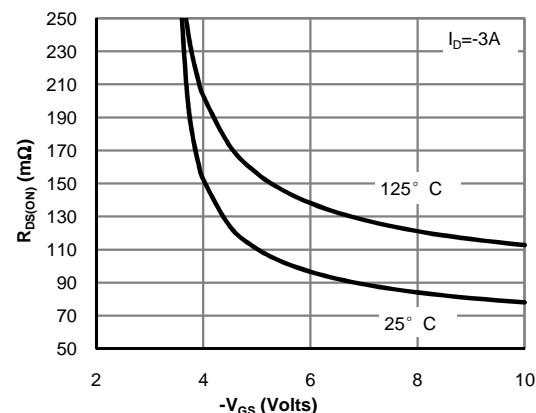
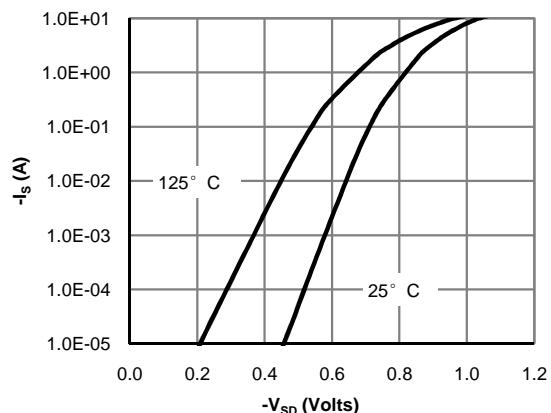


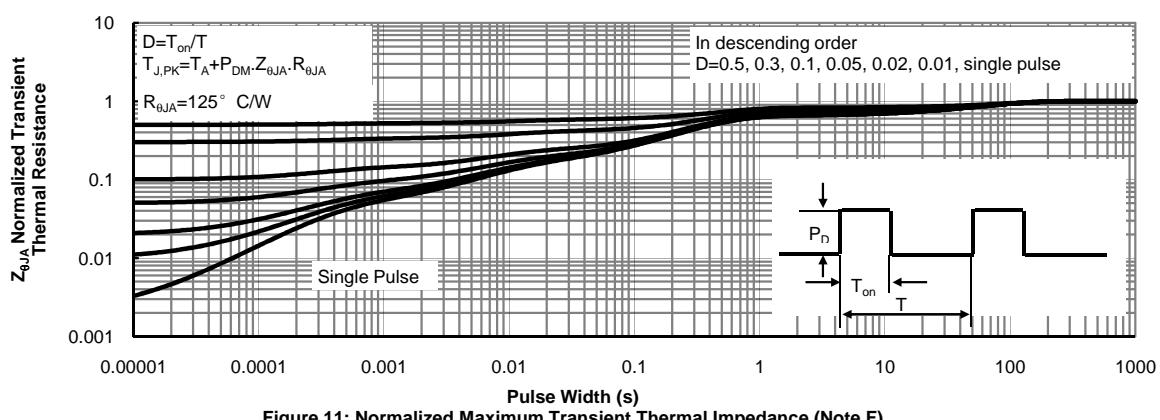
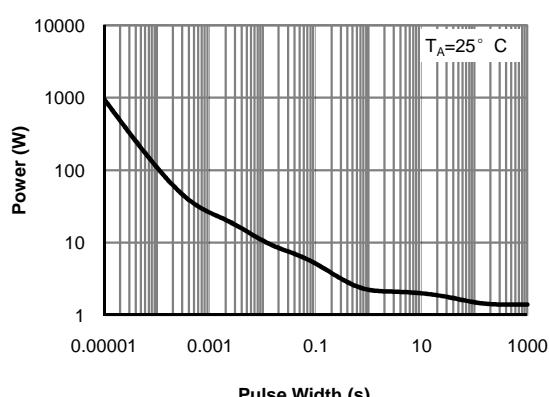
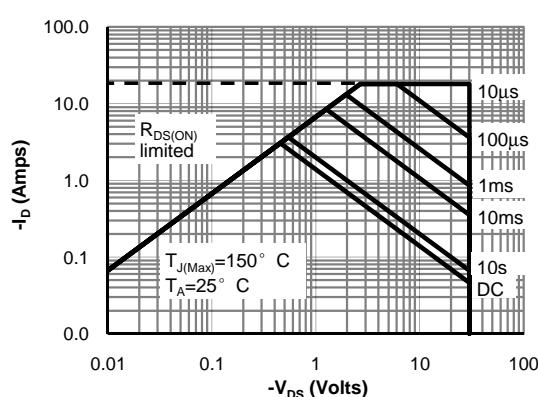
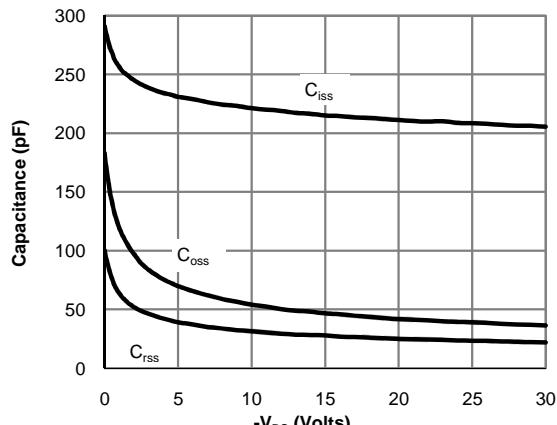
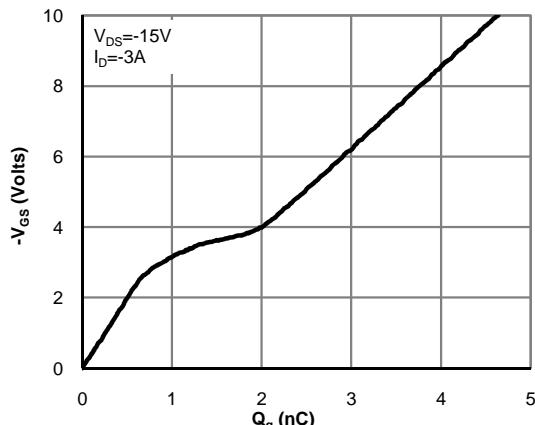
Absolute Maximum Ratings $T_A=25^\circ\text{C}$ unless otherwise noted

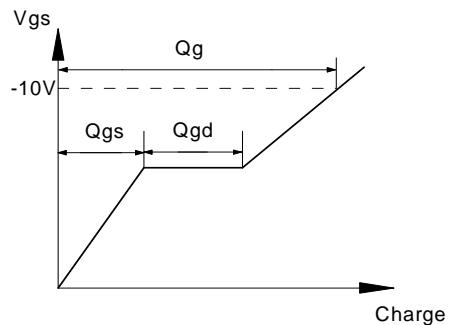
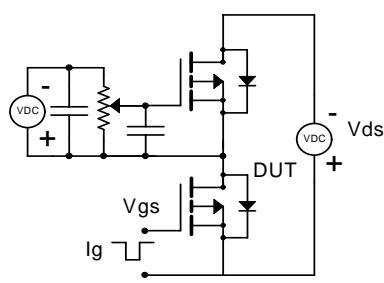
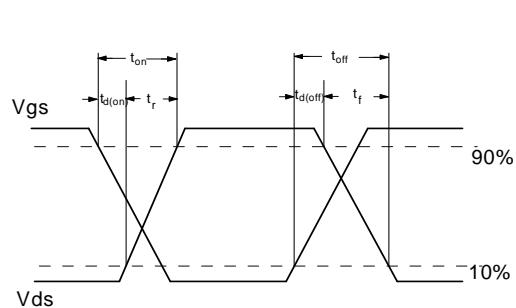
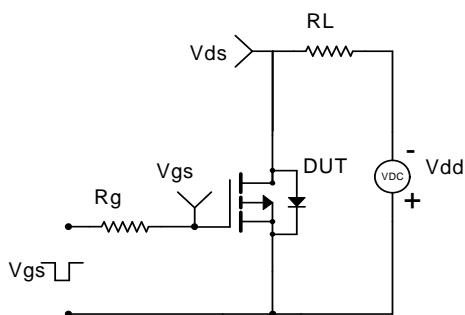
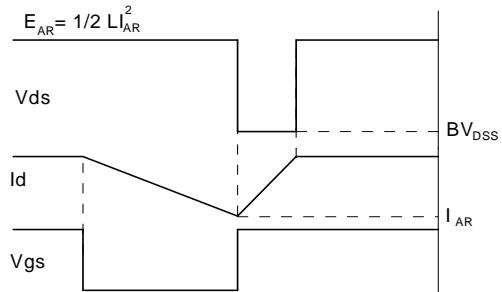
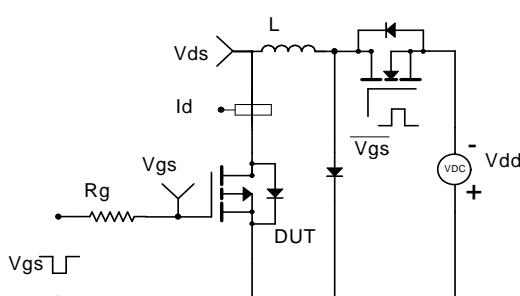
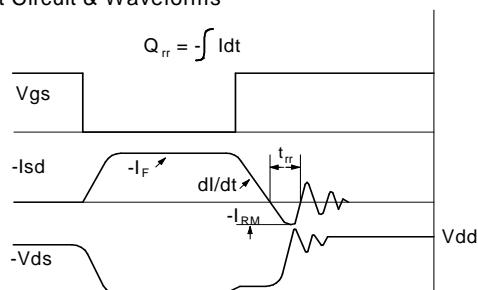
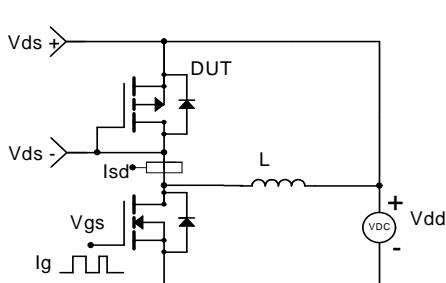
Parameter	Symbol	Maximum	Units
Drain-Source Voltage	V_{DS}	-30	V
Gate-Source Voltage	V_{GS}	± 20	V
Continuous Drain Current <small>$T_A=25^\circ\text{C}$</small>	I_D	-3	A
		-2	
Pulsed Drain Current ^C	I_{DM}	-18	
Power Dissipation ^B <small>$T_A=25^\circ\text{C}$</small>	P_D	1.4	W
		0.9	
Junction and Storage Temperature Range	T_J, T_{STG}	-55 to 150	°C

Thermal Characteristics

Parameter	Symbol	Typ	Max	Units
Maximum Junction-to-Ambient ^A <small>$t \leq 10\text{s}$</small>	$R_{\theta JA}$	70	90	°C/W
Maximum Junction-to-Ambient ^{A,B} <small>Steady-State</small>		100	125	°C/W
Maximum Junction-to-Lead	$R_{\theta JL}$	63	80	°C/W

TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS

Fig 1: On-Region Characteristics (Note E)

Figure 2: Transfer Characteristics (Note E)

Figure 3: On-Resistance vs. Drain Current and Gate Voltage (Note E)

Figure 4: On-Resistance vs. Junction Temperature (Note E)

Figure 5: On-Resistance vs. Gate-Source Voltage (Note E)

Figure 6: Body-Diode Characteristics (Note E)

TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS


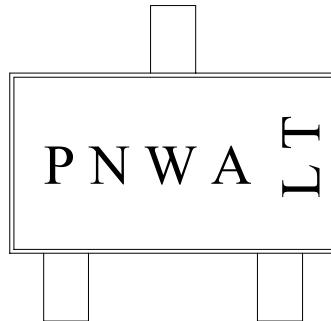
Gate Charge Test Circuit & Waveform

Resistive Switching Test Circuit & Waveforms

Unclamped Inductive Switching (UIS) Test Circuit & Waveforms

Diode Recovery Test Circuit & Waveforms




ALPHA & OMEGA
SEMICONDUCTOR

Document No.	PD-01839
Version	B
Title	AO3421E Marking Description

SOT-23 PACKAGE MARKING DESCRIPTION



Green product

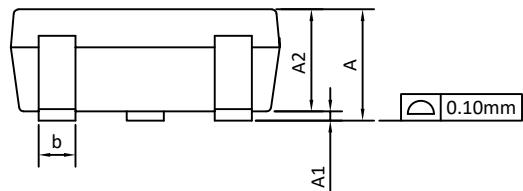
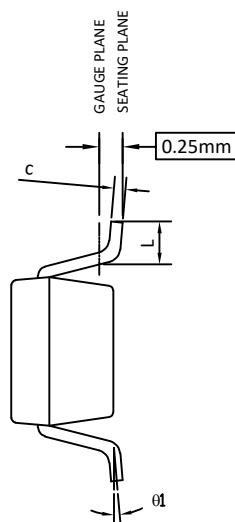
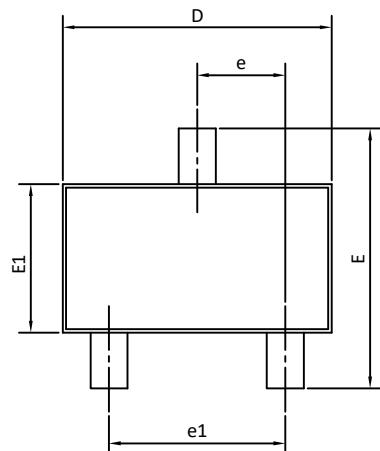
NOTE:

- PN - Part number code
- W - Year and week code
- A - Assembly location code
- L&T - Assembly lot code

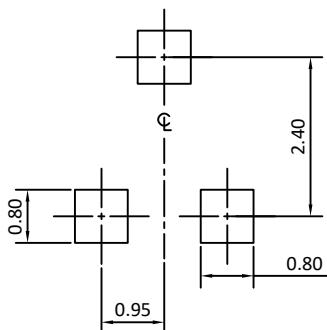
PART NO.	DESCRIPTION	CODE (PN)
AO3421E	Green product	RP
AO3421EL	Green product	RP



SOT23 PACKAGE OUTLINE



RECOMMENDED LAND PATTERN



UNIT: mm

SYMBOLS	DIMENSION IN MM			DIMENSION IN INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.85	---	1.25	0.033	----	0.049
A1	0.00	---	0.15	0.000	----	0.006
A2	0.70	1.05	1.20	0.028	0.041	0.047
b	0.30	0.40	0.50	0.012	0.016	0.020
c	0.08	0.13	0.20	0.003	0.005	0.008
D	2.80	2.90	3.10	0.110	0.114	0.122
e	0.95 BSC			0.037 BSC		
e1	1.90 BSC			0.075 BSC		
E	2.60	2.80	3.00	0.102	0.110	0.118
E1	1.40	1.60	1.80	0.055	0.063	0.071
L	0.30	---	0.60	0.012	----	0.024
Q1	0°	5°	8°	0°	5°	8°

NOTE:

1. PACKAGE BODY SIZES EXCLUDE MOLD FLASH OR GATE BURRS.
MOLD FLASH AT THE NON-LEAD SIDES SHOULD BE LESS THAN 5 MILS EACH.
2. TOLERANCE ± 0.100 mm (4 mil) UNLESS OTHERWISE SPECIFIED.
3. DIMENSION L IS MEASURED IN GAUGE PLANE.
4. CONTROLLING DIMENSION IS MILLIMETER. CONVERTED INCH DIMENSIONS ARE NOT NECESSARILY EXACT.
5. ALL DIMENSIONS ARE IN MILLIMETERS.



ALPHA & OMEGA
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AOS Semiconductor Product Reliability Report

AO3421E, rev B

Plastic Encapsulated Device

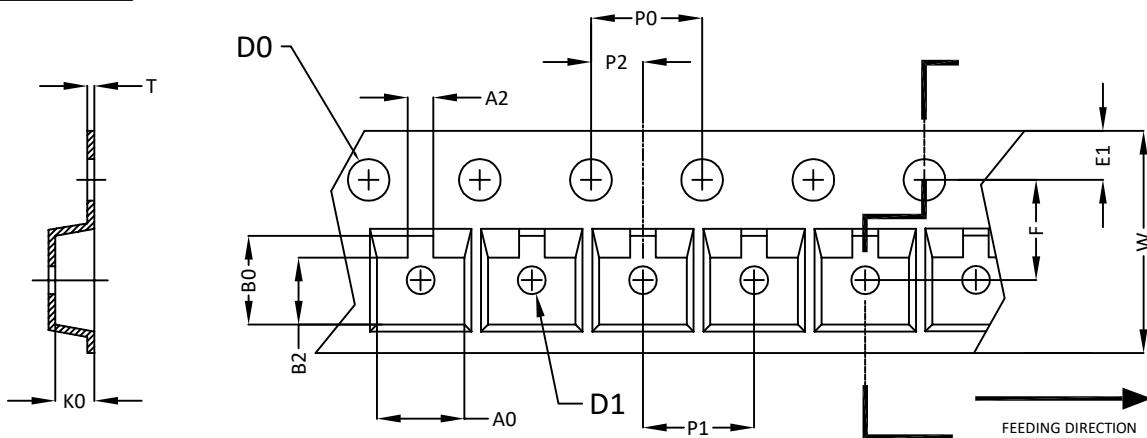
ALPHA & OMEGA Semiconductor, Inc

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Feb. 2018



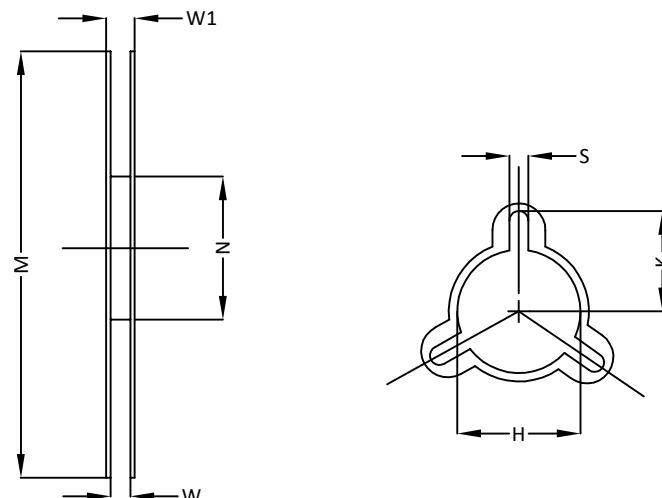
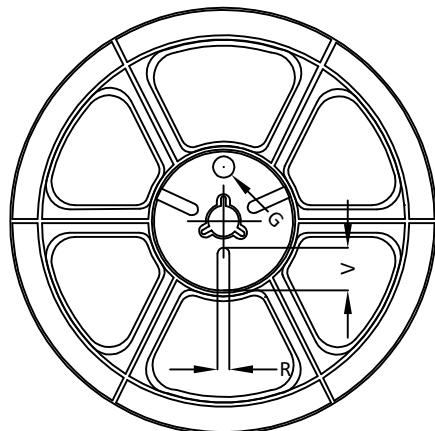
SOT23 Carrier Tape



UNIT: MM

PACKAGE	A0	B0	K0	D0	D1	W	E1	F	P0	P1	P2	T	A2	B2
SOT23-3L (8 mm)	3.05 - 3.40	3.00-3.38	1.20- 1.47	1.55 ±0.05	1.00 ±0.25	8.00 ±0.30	1.75 ±0.10	3.50 ±0.05	4.00 ±0.10	4.00 ±0.10	2.00 ±0.05	0.18 -0.25	0.84-1.24	2.29-2.69

SOT23 Reel



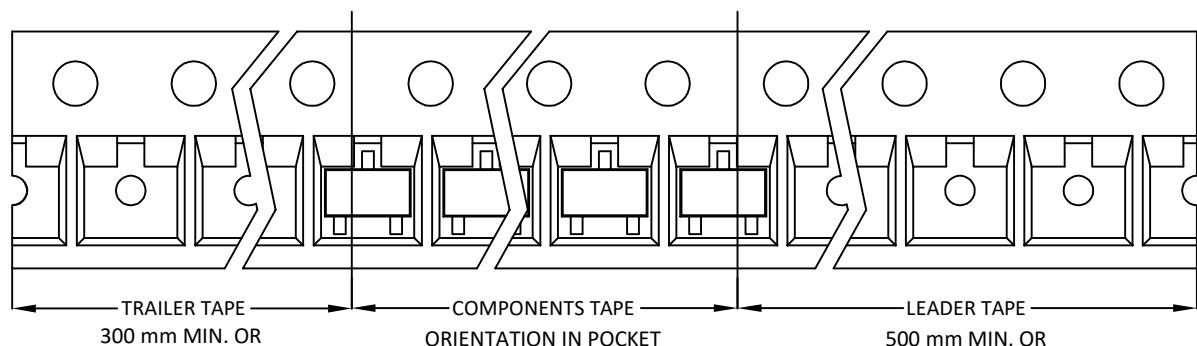
UNIT: MM

TAPE SIZE	REEL SIZE	M	N	W	W1	H	K	S	G	R	V
8 mm	Ø178	Ø178.00 ±1.00	Ø54.00 ±0.50	9.00 ±0.30	11.40 ±1.00	Ø13.00 +0.50 -0.20	10.60	2.00 ±0.50	Ø9.00	5.00	18.00

SOT23 Tape

Leader / Trailer
& Orientation

Unit Per Reel:
3000pcs



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[BSO203SP](#) [BSO211P](#) [IPA60R230P6](#) [IPA60R460CE](#)